MBR2515L

SWITCHMODE[™] **Power Rectifier**

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 100°C Operating Junction Temperature
- 25 A Total
- Pb-Free Packages are Available*

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics

- Case: Epoxy, Molded
- Epoxy Meets UL 94, V-0 @ 0.125 in
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperatures for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating: Human Body Model 3B Machine Model C

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



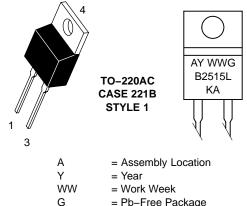
ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 25 AMPERES, 15 VOLTS



MARKING DIAGRAM



- = Pb-Free Package
- B2515L = Device Code

= Diode Polarity

ORDERING INFORMATION

KA

Device	Package	Shipping
MBR2515L	TO-220	50 Units/Rail
MBR2515LG	TO–220 (Pb–Free)	50 Units/Rail

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	15	V	
Average Rectified Forward Current (T _C = 91°C per Device)	I _{F(AV)}	25	A	
Peak Repetitive Forward Current, per Leg (Square Wave, 20 kHz, $T_C = 95^{\circ}C$)	I _{FRM}	25	А	
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions, Halfwave, Single Phase, 60 Hz)	I _{FSM}	150	A	
Peak Repetitive Reverse Surge Current (2.0 µs, 1.0 kHz)	I _{RRM}	1.0	А	
Storage Temperature Range	T _{stg}	-65 to +125	°C	
Operating Junction Temperature	Т _Ј	-65 to +100	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

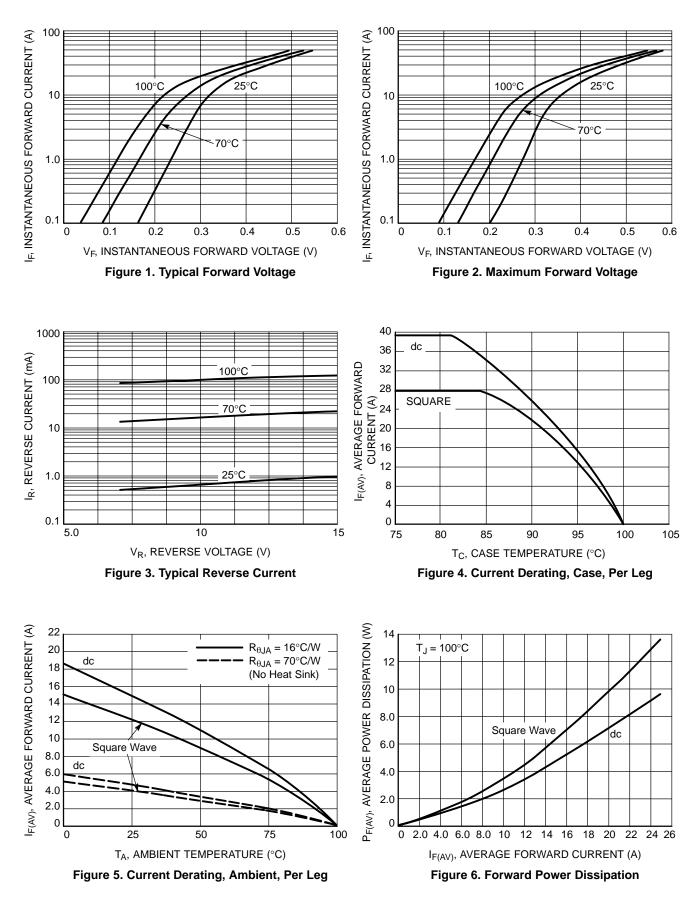
THERMAL CHARACTERISTICS

Characteristic	Conditions	Symbol	Max	Unit
Maximum Thermal Resistance, Junction-to-Case	Min. Pad	$R_{\theta JC}$	1.0	°C/W
Maximum Thermal Resistance, Junction-to-Ambient	Min. Pad	R_{\thetaJA}	70	

ELECTRICAL CHARACTERISTICS

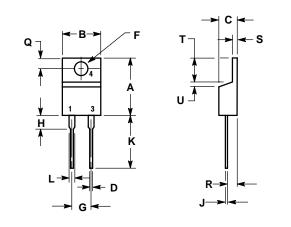
Characteristic		Min	Typical	Max	Unit
Instantaneous Forward Voltage (Note 1) ($i_F = 25 \text{ Amps}, T_j = 25^{\circ}\text{C}$) ($i_F = 25 \text{ Amps}, T_j = 70^{\circ}\text{C}$) ($i_F = 19 \text{ Amps}, T_j = 70^{\circ}\text{C}$)		- - -	0.41 0.37 0.34	0.45 0.42 0.38	V
Instantaneous Reverse Current (Note 1) (Rated dc Voltage, Tj = 25°C) (Rated dc Voltage, Tj = 70°C)	i _R	- -	1.0 24	15 200	mA

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.



PACKAGE DIMENSIONS

TO-220 PLASTIC CASE 221B-04 ISSUE D



NOI	ES:
1.	DIMENSIONING AND TOLERANCING PER ANSI
	V1/ 5M 1082

2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.595	0.620	15.11	15.75	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.82	
D	0.025	0.035	0.64	0.89	
F	0.142	0.147	3.61	3.73	
G	0.190	0.210	4.83	5.33	
Н	0.110	0.130	2.79	3.30	
J	0.018	0.025	0.46	0.64	
Κ	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.14	1.52	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.14	1.39	
Т	0.235	0.255	5.97	6.48	
U	0.000	0.050	0.000	1.27	

STYLE 1: PIN 1. CATHODE 2. N/A 3. ANODE 4. CATHODE

SWITCHMODE is a trademark of Semiconductor Components Industries, LLC.

ON Semiconductor and IIII are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other application in which the failure of the SCILLC product create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use persons, and reasonable attorney fees andising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use persons and sensing out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized to applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5773–3850 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative